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Arizona State University NanoFab

FILMETRICS F20 STANDARD OPERATION PROCEDURE

Rev D

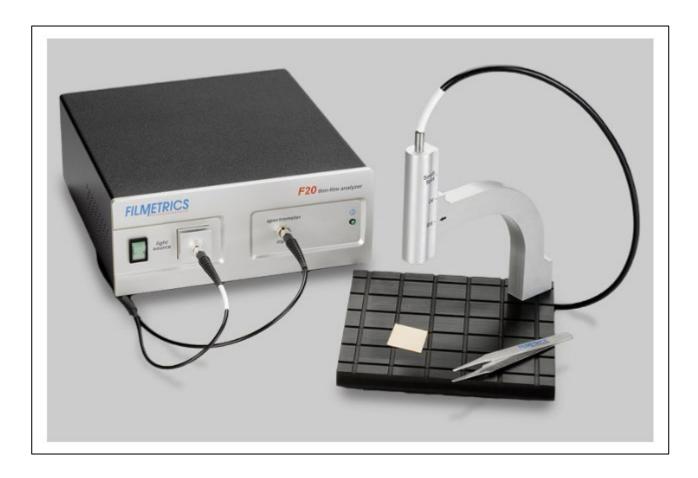




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1.0 Purpose / Scope

- 1.1 Our Filmetrics F20 uses spectroscopic reflecting light, then analyzes this light over a range of wavelengths. The thicker the film, the more oscillations. The amplitude of the oscillations will help determine by the refractive index *n* and extinction *k* coefficients of the films and substrate. Single layer or multilayer films on substrates can be measured and analyzed. Typically, the F20 will measure thickness values between 150Å and 50um. The large spot size is about 1.5mm diameter.
- 1.2 This measurement device will be able to measure visible light from 400nm to 850nm wavelengths.

2.0 Reference Documents

2.1 Filmetrics F20 manual from Filmetrics.com. The PDF document is available on the computer desktop.

3.0 Equipment/Supplies

- 3.1 Clean silicon reference wafer.
- 3.2 Tweezers to handle wafers
- 3.3 Light is supplied by a tungsten-halogen bulb that generates light from 375nm to 3000nm.

4.0 Safety

- 4.1 Follow all safety procedures outlined in the NanoFab Handbook
- 4.2 Follow safety and handling procedures when working with vacuum systems and source materials.
- 4.3 Do not attempt to repair the tool under any circumstances. Submit a service request and contact ASU NanoFab staff.

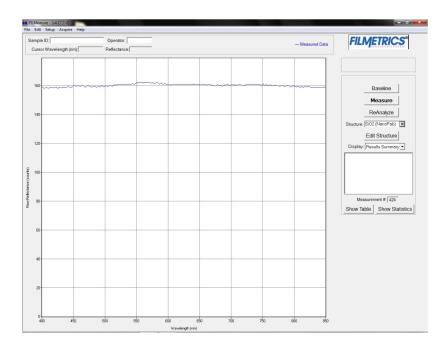


5.0 Baseline Calibration

- 5.1 Ensure the light is on at the front of the Filmetrics light source detector unit. Ensure the light bulb has been on for at least 5 minutes.
- 5.2 Ensure the Filmetrics "FILMeasure" software is open or double click on the icon.
- 5.3 Performing the Baseline calibration.

Note: It is recommended to perform Baseline calibrations every 20-30 minutes due to potential drift of the data.

- 5.3.1 Place a clean Silicon sample and place under the F20 fiber optic detector on the sample stage.7x
- 5.3.2 Depress Baseline button on the right margin display.
- 5.3.3 Take Reflectance Reference: Step One: Set your Reference Material. In most cases it will be Silicon.
- 5.3.4 Depress OK. Take Reference reading.
- 5.3.5 Setup: The Dark Scan could be taken with no sample on the sample stage. The tool is looking for a loss of light reflection. Depress OK.
- 5.3.6 The F20 is now ready to make measurements. The screen will show raw reflectance.



6.0 Measurement Procedures

- 6.1 Place your sample wafer on the sample stage under the fiber optic beam.
- 6.2 Select the Structure pull down menu and select your intended Recipe.
- 6.3 Depress OK to Do you want to load another Recipe.



- 6.4 Select the User Recipe you intend to use to model your measurement.
- 6.5 Select Edit Structure button to view Structure selection.
- 6.6 Edit Structure Layers Tab.
 - 6.6.1 Ensure the intended material layers on the recipe are correct or require updating.
 - 6.6.2 Enter an approximate film thickness if known.
 - 6.6.3 Checking the Fit boxes ensures the parameters is considered for the fitting of the data. This will include D (Thickness), *n* and *k* and R (Roughness).
 - 6.6.4 Select or deselect Fit boxes or options ultimately to improve the Goodness of Fit (GOF) value

	yers Angstrom (Å)	Solver Options	Solver Constraints	Alarms	ReAnalyze
Units:		Enable Robus			
	Medium	Material Air	t Thickness Only - Thickness — Roughness (r)	—— Measure ———	Edit Structure
 € Г 	1	SiO2 (Cauchy) Nano 💌	1000 0	⊽d ⊽n ⊏k ⊏r	
	Substrate	Si	Ø	□ n □ k □ r	Veasurement # 424 Table Show Statis

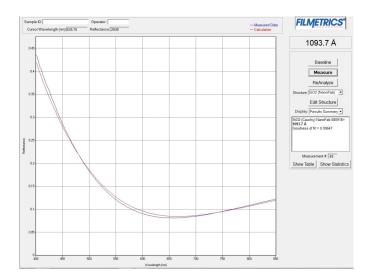
- 6.7 Edit Structure Solver Option Tab.
 - 6.7.1 The Grid method searches the entire allowed thickness range to find best initial thickness.
 - 6.7.2 The Fourier search for thickness analyzes the oscillations present in the spectrum and determines the film thickness.
 - 6.7.3 Measurement Type will remain Reflection.
 - 6.7.4 Analyzed Data: The wavelengths of the spectrum used for measurements are adjustable from beyond 400-850nm.



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ructure Name: 02 (NanoFab) PECVD 💌	м	Author: Unknown User od. Date: 8/17/2018 3:39:56 Pt
Layers Solver Op	tions Solver Constraints	Alarms
SolVing Details If gid search for thickness Equirer search for thickness Account for Back Reflections Account for Solon planently nk Model Medium Leyer 1	Convergence Criteria GOF greater 0.999 Maximum 400 Measurement Type C	Analyzed Data C Displayed Data Fixed Range From 550 nm To 1030 nm Display Datais Wavelength for n and K display.
Substrate Bridge Lorentzian-3Term 🔄	C Iransmittance	and k display. 632.8 nm Layer Options □ Lock Together Identical Layers

- 6.8 Please do not Save changes to the current Recipe.
- 6.9 Depress the Measure button to display reflectance and evaluate the thickness values and GOF parameters.
- 6.10 Depress the ReAnalyze button when trying different analysis settings on a previously acquired spectrum.
- 6.11 The displayed spectrum displays the measured data (Blue) and calculated model (Red) reflections. The measured data and the calculated will be close if the selected recipe matches the film.



- 6.12 Recommendations for improved accuracy.
 - 6.12.1 Restricting the wavelength can be helpful if n and k are not accurate over the whole wavelength range.
 - 6.12.2 Slight amounts of surface or interface roughness may be present that will decrease the accuracy of the measurements.



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7.0 Current Materials types

	Dimit	D		
Acrylic	AZ7510	In As	🔳 Si	TiO2
Ag	AZ7700	InGaAs	i Si_Am	TiSi2
AI	AZEL2015	InGaAs24P76	Si_Poly	UV2HSDUV
AL2O3 NanoFab 081318	AZNOVA2071	InGaAs42P58	Si_Poly_Brugg	UV3DUV
AI2O3	AZOFPR-800	InGaAs55P45	i Si3N4 (Si Rich)	UV5DUV
Al10Ga90As	a Azp4110	InGaAs82P18	iii Si3N4	UV6DUV
Al20Ga80As	📄 BARLi	🔳 InP	🛋 Si3N4-thin	a w
Al30Ga70N	BaTiO3	InSb (1997)	SiC	XHRiC-16
Al32Ga68As	📑 bk7	Insulator	SiN (cauchy) JianxingZhang(07012019)	XR-1504
Al42Ga58As	Black Diamond	🖬 по	SiN (Cauchy) NanoFab 080818	ZnS
Al49Ga51As	BSG	KCI	SiN (Cauchy) NanoFab 082318	ZnS_cub
AI59Ga41As	CaF2	Level M10	SiO SiO	ZnSe
Al70Ga30As	Carbon_Am	📄 ma-N-2403	SiO2 (cauchy) JianxingZhang(07012019)	ZrO2
Al80Ga20As	CDdye	MgF2	SiO2 (Cauchy) NanoFab 080918	
Al90Ga10As	CdS	Mg0	SiO2	
AIAs	CdTe	I Mo	SiON (Cauchy) NanoFab 082318	
AlCu	Co	🗐 Ni	SP570	
AlGaAs	CORAL	I NIP	SPR2FX13	
AIN	CoSi2	Parylene	SPR2FX13JL	
AION	CoWP	PbS	SPR2FX13JM	
AISb	Cr Cr	PbSe	SPR500A	
APEXE	CR39	PET	SPR700	
AQUATAR	Cu	PI-2611 (Cured)	SPR850	
AR2600DUV	Diamond	PI-2611 (Soft Baked)	SPR900	
ArFS05	I DLC	PMA	SPR950	
ArFS10A	DLCARBON	PMMA 950Polymer (Cauchy) NanoFab 092118	SPR955CM	
Au	EL6 Co-Polymer (Cauchy) NanoFab 092118	PMMA	SPR3000	
AZ 12XT	EL11 Co-Polymer (Cauchy) NanoFab 092118	Polycarb	SPR3500	
AZ 15nXT	Fe203	Polyolef	Stainless Steel	
AZ nLOF 2000	a ga2o3	Polystyr	Image: SU-8 2002	
AZ nLOF	GaAs	Pt	SUSTEM8	
AZ P4000	GaN	PVA alcohol	T1-SiO2	
AZ1518	GaP	PyrolyticNitride	Ta	
AZ3312	GaSb	PZT	ThermalOxide	
AZ6112	Gaso Ge	Quartz	Ti	
AZ6210B	HfO2 (Cauchy) NanoFab 081318	Rh	TiN	
		RTC		
AZ7209	HfO2		TiN-Palik	

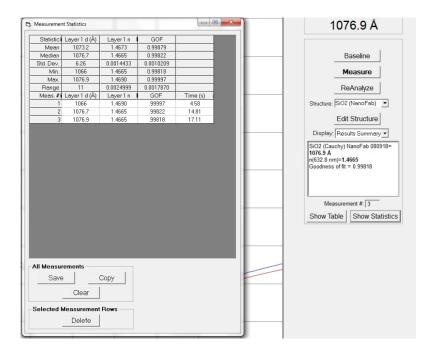


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8.0 Measurement Statistics

- 8.1 On the right column is a button labeled Show Statistics. Select this box to open the window containing data.
 - 8.1.1 Mean, Medium, Std. Dev., Min, Max, Range row values.
- 8.2 Followed by a table of values with headings, Measure #, Layer 1 d(A), GOF commands at the bottom are Save (to CSV), Copy, Clear or selected rows to delete.



9.0 Revision History

Effective Date	Originator	DESCRIPTION OF REVISION	Issue
05/05/09	Name	Initial Release	А
	Staff	Rev B	В
04/21/15	Wayne Paulson	Rev C update & fit new SOP format	С
08/16/19	Jaime Quintero	Checklist format	D